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2N3866 2N3866A

NPN SILICON HIGH FREQUENCY TRANSISTOR



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UNITS

V

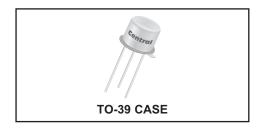
°C/W

DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N3866 and 2N3866A are Silicon NPN RF Transistors, mounted in a hermetically sealed package, designed for high frequency amplifier and oscillator applications.

35

MARKING: FULL PART NUMBER



MAXIMUM RATINGS: (T_A=25°C unless otherwise noted)
SYMBOL
Collector-Base Voltage V_{CBO} 55
Collector-Emitter Voltage V_{CEO} 30

V Emitter-Base Voltage V_{EBO} 3.5 ٧ Continuous Collector Current I_{C} 0.4 Α Continuous Base Current 2.0 Α I_B Power Dissipation (T_C=25°C) W P_{D} 5.0 Operating and Storage Junction Temperature T_J, T_{stg} -65 to +200 °C

 Θ_{JC}

Thermal Resistance

FLECTRICAL CHARACTERISTICS: (T_A=25°C unless otherwise noted)

	AL CHARACTERISTICS: (TA=25°C unless otherwis	se notea)		
SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
ICEO	V _{CE} =28V		20	μA
ICEV	V_{CE} =55V, $V_{BE(OFF)}$ =1.5V		0.1	mA
ICEV	$V_{CE}=30V, V_{BE(OFF)}=1.5V, T_{C}=200^{\circ}C$		5.0	mA
I _{EBO}	V _{EB} =3.5V		0.1	mA
BV CER	I_C =5.0mA, R_{BE} =10 Ω	55		V
BVCBO	I _C =500μA	55		V
BVCEO	I _C =5.0mA	30		V
BV EBO	I _E =100μA	3.5		V
V _{CE} (SAT)	I _C =100mA, I _B =20mA		1.0	V
hFE	V _{CE} =5.0V, I _C =50mA (2N3866)	10	200	
h _{FE}	V _{CE} =5.0V, I _C =50mA (2N3866A)	25	200	
hFE	V _{CE} =5.0V, I _C =360mA	5.0		
f_{T}	V _{CE} =15V, I _C =50mA, f=200MHz (2N3866)	500		MHz
f_{T}	V _{CE} =15V, I _C =50mA, f=200MHz (2N3866A)	800		MHz
C_{ob}	V_{CB} =28V, I_E =0, f=1.0MHz		3.0	pF
GPE	V _{CC} =28V, P _{out} =1.0W, f=400MHz (Figure 1)		10	dB
η	V _{CC} =28V, P _{out} =1.0W, f=400MHz (Figure 1)		45	%

R2 (15-September 2010)

2N3866 2N3866A





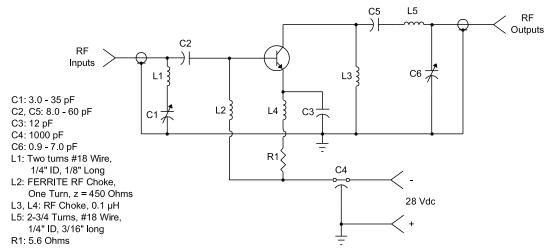
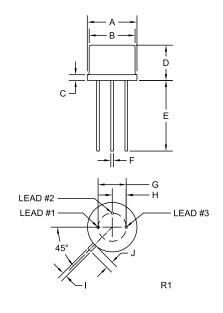


Figure 1. 400MHz Test Circuit

TO-39 CASE - MECHANICAL OUTLINE



DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
A (DIA)	0.335	0.370	8.51	9.40			
B (DIA)	0.315	0.335	8.00	8.51			
С	-	0.040	-	1.02			
D	0.240	0.260	6.10	6.60			
Е	0.500	-	12.70	-			
F (DIA)	0.016	0.021	0.41	0.53			
G (DIA)	0.200		5.08				
Н	0.100		2.54				
	0.028	0.034	0.71	0.86			
J	0.029	0.045	0.74	1.14			
TO 20 (DEV/, D4)							

TO-39 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

MARKING: FULL PART NUMBER

R2 (15-September 2010)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

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- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- · Special wafer diffusions
- PbSn plating options
- · Package details
- · Application notes
- · Application and design sample kits
- Custom product and package development

CONTACT US

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